

USN

--	--	--	--	--	--	--	--	--	--

Third Semester B.E. Degree Examination, Jan./Feb. 2023 Analog Electronics

Max. Marks: 100

Note: Answer any FIVE full questions, choosing ONE full question from each module.

Module-1

- 1 a. Derive an expression to find the input impedance output impedance and voltage gain of a transistor connected in CE mode using voltage divider biasing. Use r_e model. (08 Marks)
- b. For the circuit shown in Fig. Q1 (b), find r_e , z_i , z_o and A_v and A_i with $r_o = \infty$. If r_o is changed to $50 \text{ k}\Omega$, calculate z_i , A_v , A_i and Z_o and compare the results obtained with $r_o = \infty$. (08 Marks)

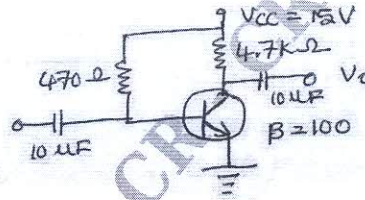


Fig. Q1 (b)

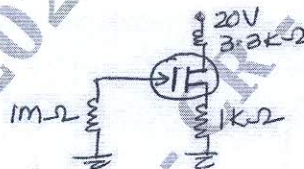
- c. Mention the important characteristics of emitter follower. (04 Marks)

OR

- 2 a. Draw the AC equivalent circuit of a emitter follower configuration and using approximate h-model find an expression to calculate the input impedance, output impedance, voltage gain and current gain. (10 Marks)
- b. Find an expression to calculate the input impedance, voltage gain and output impedance of a transistor using complete hybrid model. (10 Marks)

Module-2

- 3 a. Compare BJT with FET. (04 Marks)
- b. For the circuit shown in Fig. Q3 (b), calculate (i) V_{GSQ} (ii) I_{DQ} (iii) V_{DS} (iv) V_S (v) V_G and (vi) V_D . (08 Marks)



$$V_{DSS} = 8 \text{ mA}$$

$$V_P = -6 \text{ V}$$

Fig. Q3 (b)

- c. Derive an expression to find the input impedance, output impedance and voltage gain of a n channel FET using common gate configuration. (08 Marks)

OR

- 4 a. Draw the construction of depletion type MOSFET and explain ion drain and transfer characteristic. (08 Marks)
- b. Draw the ac equivalent circuit of JFET connected in common source configuration and find the expression to calculate input impedance, output impedance and voltage gain assume self bias. (08 Marks)
- c. Sketch the small signal ac model of an FET and find the value of transconductance g_m and r_d if $Y_{fs} = 4 \text{ mS}$ and $Y_{os} = 33.33 \text{ }\mu\text{S}$. (04 Marks)

Important Note : 1. On completing your answers, compulsorily draw diagonal cross lines on the remaining blank pages.
2. Any revealing of identification, appeal to evaluator and/or equations written eg. 42+8 = 50, will be treated as malpractice.

Module-3

- 5 a. Explain the low frequency response of BJT amplifier. (10 Marks)
 b. Calculate the low frequency cut off for the network shown in Fig.Q5 (b) using the following values :
 $C_G = 0.01 \mu\text{F}$, $C_C = 0.5 \mu\text{F}$, $C_S = 2 \mu\text{F}$, $R_{\text{sig}} = 10 \text{ K}\Omega$, $R_G = 1 \text{ M}\Omega$, $R_D = 4.7 \text{ K}\Omega$,
 $R_S = 1 \text{ K}\Omega$, $R_L = 2.2 \text{ K}\Omega$, $I_{\text{DSS}} = 8 \text{ mA}$, $V_P = -4 \text{ V}$, $r_o = \infty$, $V_{\text{DD}} = 20 \text{ V}$. (10 Marks)

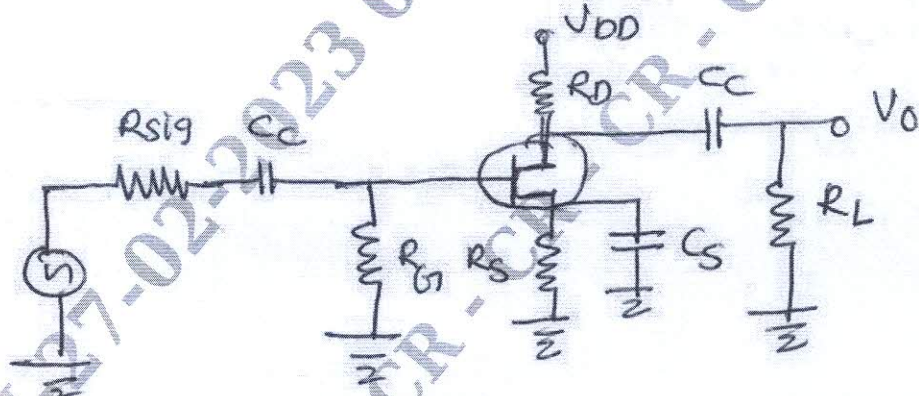


Fig. Q5 (b)

OR

- 6 a. What is Miller effect capacitance? Find an expression to calculate the input Miller capacitance and output Miller capacitance. (10 Marks)
 b. Explain the high frequency response of an BJT amplifier. (10 Marks)

Module-4

- 7 a. Find an expression to calculate the input impedance, output impedance and voltage gain of current series feedback amplifier. (08 Marks)
 b. An amplifier has a bandwidth of 200 kHz and voltage gain of 1000. find (i) the change in band width and gain if 5% negative feedback introduced (ii) to get a band width of 1 MHz, what is the amount of feedback required. (08 Marks)
 c. Write the advantages of negative feedback. (04 Marks)

OR

- 8 a. Draw the circuit diagram of a weinbridge oscillator and explain its working. (06 Marks)
 b. In a transistor Colpitts oscillator the inductor used is 1 mH and $h_{fe} = 150$. Find the value of C_1 and C_2 to produce oscillations of 120 kHz. (06 Marks)
 c. Explain the working of UJT relaxation oscillator. (08 Marks)

Module-5

- 9 a. Explain how power amplifiers can be classified based on the location of Q point. (04 Marks)
 b. Draw the circuit diagram of transformer coupled class A power amplifier and show the maximum conversion efficiency is equal to 50%. (08 Marks)
 c. A Class B push pull amplifier is operated with $V_{CC} = 25 \text{ V}$ and $R_L = 8 \Omega$, find (i) the maximum input power (ii) maximum output power and (iii) maximum circuit efficiency. (08 Marks)

OR

- 10 a. Draw the circuit of series voltage regulator using transistor and explain its operation. (08 Marks)
- b. What is regulation and write the expression for voltage regulation. If a dc supply provides 50 V under no load condition and produces 46 V under load calculate the voltage regulation. (06 Marks)
- c. Find the output voltage and zener current in regulator circuit shown in Fig. Q10 (c).

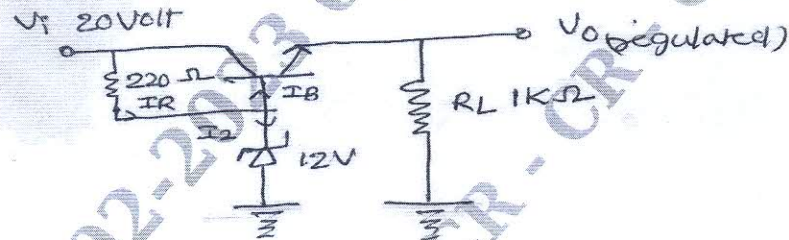


Fig. Q10 (c)

(06 Marks)

* * * * *